TOSHIBA Transistor Silicon PNP Epitaxial Type

2SA2060

High-Speed Switching Applications DC-DC Converter Applications Strobe Applications

- High DC current gain: $h_{FE} = 200$ to 500 ($I_{C} = -0.5$ A)
- Low collector-emitter saturation voltage: $V_{CE (sat)} = -0.2 \text{ V (max)}$
- High-speed switching: tf = 90 ns (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	-50	V	
Collector-emitter voltage		V _{CEO}	-50	٧	
Emitter-base voltage		V _{EBO}	-7	V	
Collector current	DC	IC	-2.0	Α	
	Pulse	I _{CP}	-3.5		
Base current		I _B	-200	mA	
Collector power dissipation	t = 10 s	PC	2.5	W	
	DC	(Note 1)	1.0		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

Unit: mm

4.6MAX. 1,6MAX. 1,6MAX. 1,6MAX. 1,7MAX. 0.4±0.05

0.45-0.05 0.4-0.05

1.5±0.1 1.5±0.1

1. Base 2. Collector (heat sink) 3. Emitter

JEDEC —

JEITA SC-62

TOSHIBA 2-5K1A

Weight: 0.05 g (typ.)

Note 1: Mounted on an FR4 board (glass epoxy, 1.6 mm thick, Cu area: 645 mm²)

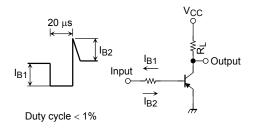
Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = -50 V, I _E = 0	_	_	-100	nA
Emitter cut-off current		I _{EBO}	V _{EB} = -7 V, I _C = 0	_	_	-100	nA
Collector-emitter breakdown voltage		V (BR) CEO	$I_C = -10 \text{ mA}, I_B = 0$	-50	_	_	V
DC current gain		h _{FE} (1)	V _{CE} = -2 V, I _C = -0.3 A	200	_	500	
		h _{FE} (2)	V _{CE} = -2 V, I _C = -1.0 A	100	_	_	
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = -1.0 A, I _B = -0.033 A	_	_	-0.2	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = -1.0 A, I _B = -0.033 A	_	_	-1.1	V
Collector output capacitance		C _{ob}	V _{CB} = −10 V, I _E = 0, f = 1 MHz	_	20	_	pF
Switching time	Rise time	t _r	See Figure 1 circuit diagram.	_	60	_	
	Storage time	t _{stg}	$V_{CC} \approx -30 \text{ V}, R_L = 30 \Omega$	_	250	_	ns
	Fall time	t _f	-l _{B1} = l _{B2} = -33 mA	_	90	_	

Marking



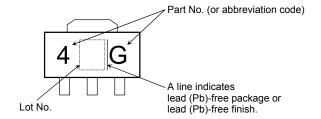
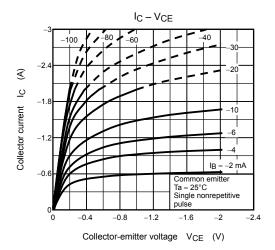
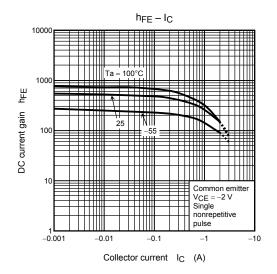
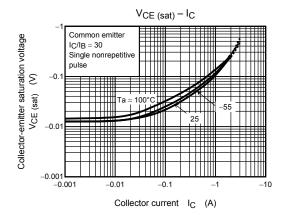
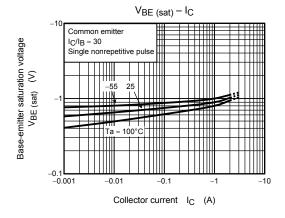


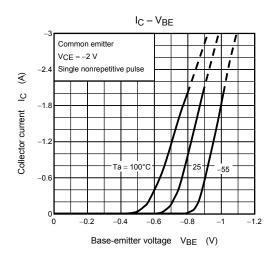
Figure 1 Switching Time Test Circuit & Timing Chart



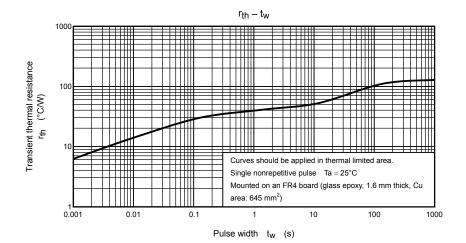


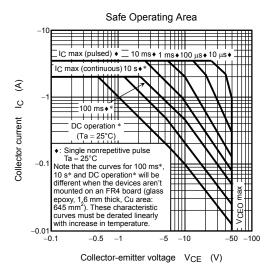






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